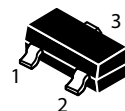
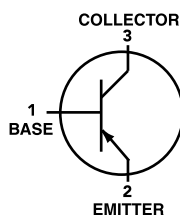


PNP General Purpose Transistors

 Lead(Pb)-Free



SOT-23

MAXIMUM RATINGS($T_A=25^{\circ}\text{C}$)

Rating	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-35	V
Collector-Emitter Voltage	V_{CEO}	-30	V
Emitter-Base Voltage	V_{EBO}	-5.0	V
Collector Current - Continuous	I_C	-500	mA
Total Device Dissipation $T_A=25^{\circ}\text{C}$	P_D	150	mW
Junction Temperature	T_j	+150	$^{\circ}\text{C}$
Storage Temperature	T_{stg}	-55 to +150	$^{\circ}\text{C}$

ELECTRICAL CHARACTERISTICS

Characteristics	Symbol	Min	Typ	Max	Unit
Collector-Base Breakdown Voltage $I_C = -100\mu A, I_E = 0A$	$V_{(BR)CBO}$	-35	-	-	V
Collector-Emitter Breakdown Voltage $I_C = -1mA, I_B = 0A$	$V_{(BR)CEO}$	-30	-	-	V
Emitter-Base Breakdown Voltage $I_E = -100\mu A, I_C = 0$	$V_{(BR)EBO}$	-5.0	-	-	V
Collector Cutoff Current $V_{CB} = -35V, I_E = 0A$	I_{CBO}	-	-	-0.1	μA
Emitter Cutoff Current $V_{EB} = -5V, I_C = 0A$	I_{EBO}	-	-	-0.1	μA

ON CHARACTERISTICS

Collector-Emitter Saturation Voltage $I_C = -100mA, I_B = -10mA$	$V_{CE(sat)}$	-	-	-0.25	V
DC Current Transfer Ration $V_{CE} = -1V, I_C = -100mA$ $V_{CE} = -6V, I_C = -400mA$	h_{FE}	70 25	- -	400 -	

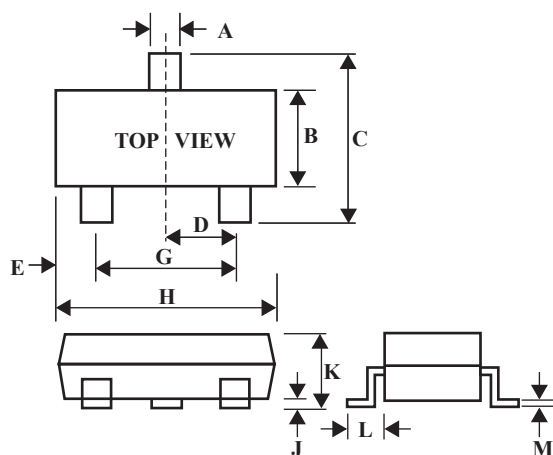
SMALL-SIGNAL CHARACTERISTICS

Transition frequency $V_{CE} = -6V, I_C = -20mA$	f_T	-	200	-	MHz
Collector Output Capacitance $V_{CE} = -6V, I_E = 0, f = 1MHz$	C_{ob}	-	13	-	pF

CLASSIFICATION h_{FE}

Rank	O	Y	GR
Range	70-140	120-240	200-400
Marking	AZO	AZY	AZG

SOT-23 Outline Dimension

**SOT-23**

Dim	Min	Max
A	0.35	0.51
B	1.19	1.40
C	2.10	3.00
D	0.85	1.05
E	0.46	1.00
G	1.70	2.10
H	2.70	3.10
J	0.01	0.13
K	0.89	1.10
L	0.30	0.61
M	0.076	0.25